MAINTENANCE MANUAL 138-174 MHz RF ASSEMBLY 19D416693G1, G2, G7, G8 AND MIXER/IF BOARDS 19C320153G1/19C331099G1, G2

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DESCRIPTION

The RF Assembly uses five tuned helical resonators to provide front end RF selectivity with no gain. A UHF preamplifier assembly is available that can be used with the receiver to improve sensitivity.

The Mixer/IF board (MIF) uses the RF signal from the RF Assembly and the mixer injection from the oscillator board to generate the IF frequency.

CIRCUIT ANALYSIS

RF ASSEMBLY

RF Pre-amplifier (Optional)

The pre-amplifier is present only in UHF receivers, and uses a dual-gate Field Effect Transistor (FET) to provide approximately 12 dB gain.

RF from the antenna is coupled through T2301 to Gate 1 of pre-amplifier Q2301. The primary of T2301 provides a 50 ohm input impedance. The amplified output at the drain terminal of Q2301 is coupled through T2302 and connected to J1 on Antenna Input board A301 through cable W2302. T2302 is tapped to provide a 50 ohm output impedance. P2301 connects to J501 on the MIF board for the regulated +10 Volt supply voltage.

Antenna Input A301/A301B

An RF signal from the antenna or UHF pre-amplifier is applied to A301 which provides an AC ground between vehicle ground and receiver A-. Resistor R1 prevents a static charge from building up on the vehicle antenna. The output of A301 is coupled through five high Q helical resonators that provide the front end RF selectivity. The helicals are tuned to the incoming frequency by C301 through C305.

MIXER-IF

Mixer & Crystal Filter

The mixer uses a FET (Q501) as the active device. The FET mixer provides a high input impedance, high power gain, and an output relatively free of harmonics (low in intermodulation products).

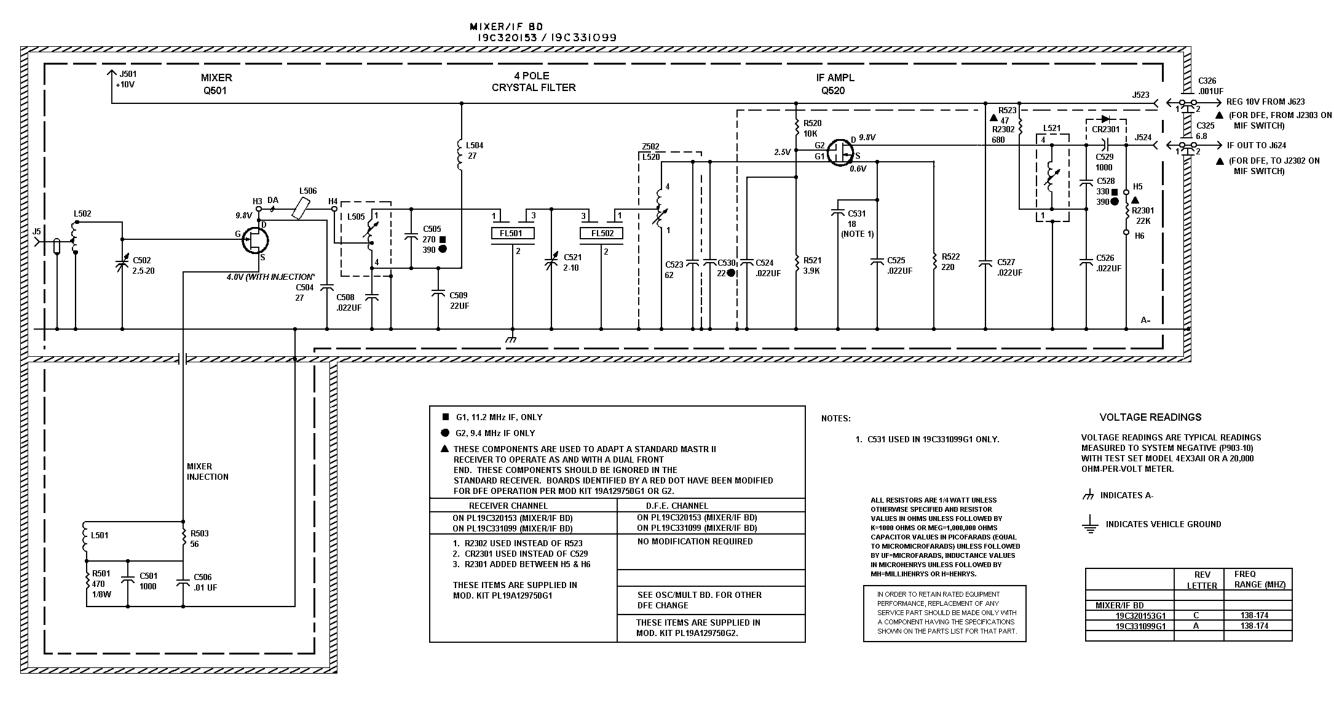
In the mixer stage, RF from the helical resonators is coupled through L502 and C502 which matches the RF output to the gate of mixer Q501. Injection voltage from the multiplier-selectivity stages is inductively coupled through L501 to the source of the mixer. The 11.2 MHz mixer IF (9.4 MHz alternate IF) output signal is coupled from the drain of Q501 through a tuned circuit (L505 and C505) which matches the mixer output to the input of the four-pole monolithic crystal filter. The highly-selective crystal filter (FL501 and FL502) provides the first portion of the receiver IF selectivity. The output of the filter is coupled through impedance-matching network L520 and C523 to the IF amplifier.



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SCHEMATIC DIAGRAM



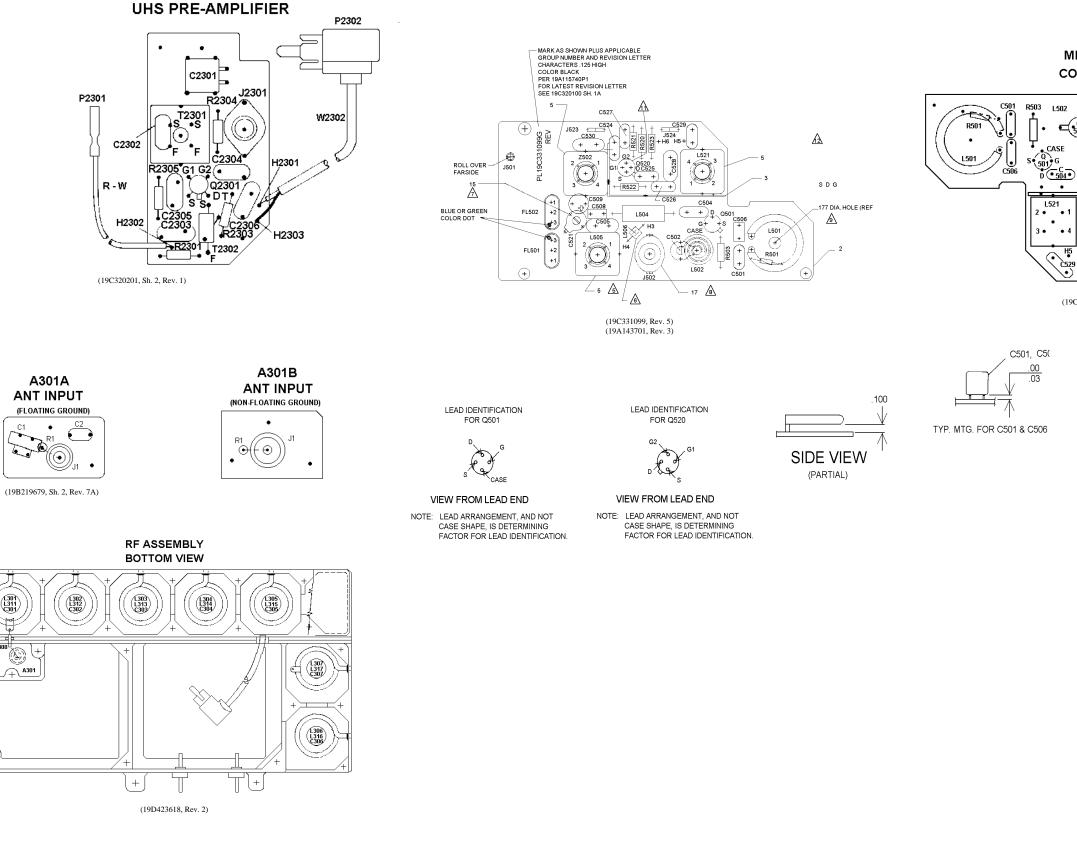
MIXER/IF BD 190320153 / 190331099

LBI-4980

	REV LETTER	FREQ Range (MHZ)
MIXER/IF BD		
19C320153G1	С	138-174
19C331099G1	Α	138-174

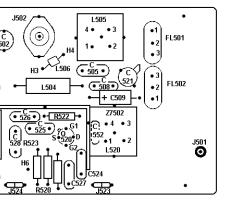
138-174 MHz MIXER/IF BOARD

(19D423478, Rev. 6)



138-174 MHz RF ASSEMBLY AND MIXER/IF BOARD





(19C321054, Sh. 2, Rev. 2)

LEAD IDENTIFICATION FOR Q501

CASE

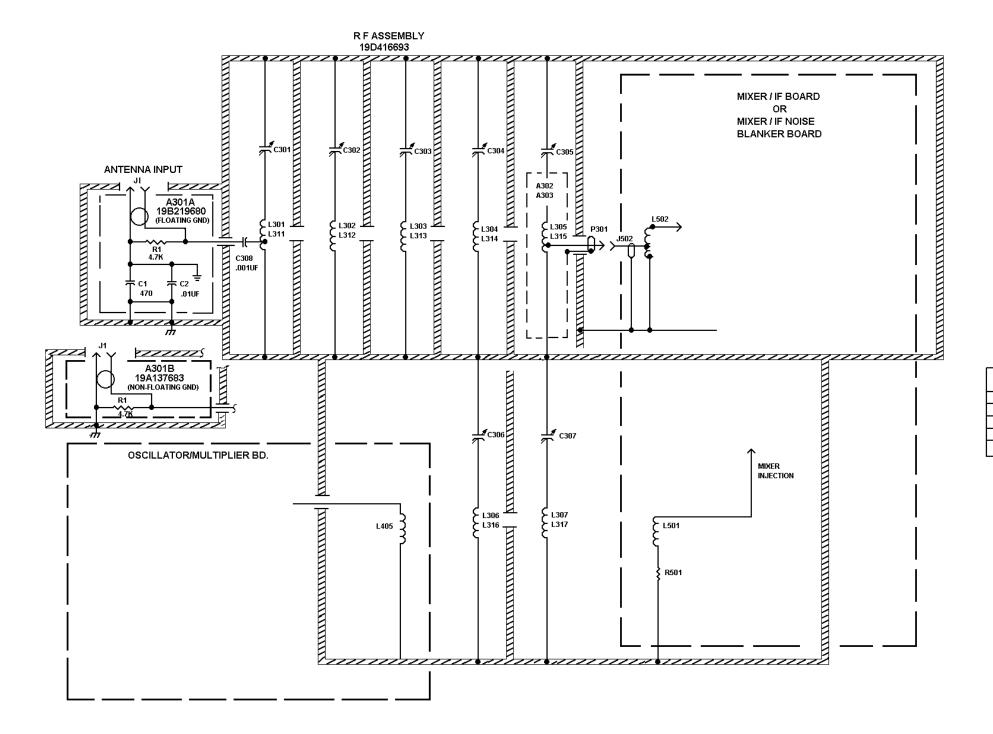
G2 S

Q520, Q2301

VIEW FROM CASE END

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

SCHEMATIC DIAGRAM





LBI-4980

ANTENNA INPUT A301		RF ASSEMBLY		FREQ Range (MHZ)
	REV LTR		REV LTR	
19680G1	-	19D4116693G1	В	138 - 155
19680G1	-	19D416693G2	С	150.8 - 174
37683G1	-	19D416693G7	Ι	138 - 155
37683G1	-	19D416693G8	-	150.8 - 174

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG = 1,000,000 OHMS. CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF = MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH = MILLIHENRYS OR H = HENRYS.

IN ORDER TO RETAIN RATED EQUIPMENT
PERFORMANCE, REPLACEMENT OF ANY
SERVICE PART SHOULD BE MADE ONLY WITH
A COMPONENT HAVING THE SPECIFICATIONS
SHOWN ON THE PARTS LIST FOR THAT PART.

VOLTAGE READINGS

VOLTAGE READINGS ARE TYPICAL READINGS MEASURED TO SYSTEM NEGATIVE (P903-10) WITH TEST SET MODEL 4EX3A11 OR A 20,000 OHM-PER-VOLT METER.

H INDICATES A-

↓ INDICATED VEHICLE GROUND

138-174 MHz RF ASSEMBLY

(19D423469, Rev. 1)

LBI-4980

PARTS LIST

			SYMBOL	PART NO.	DESCRIPTION
PARTS LIST LB/4981J 138 - 174 MHz RF ASSEMBLY,			L306 and	19B204461G18	Coil.
		MIF ASSEMBLY, UHS PRE - AMPLIFIER	L307 L311	19B216112G17	Coil.
		OHS PRE-AMPLIFIER	L312	19B216112G15	Coil.
			thru L314		
SYMBOL	PART NO.	DESCRIPTION	L316 and	19B204461G19	Coil.
STIVIBOL	PART NO.	DESCRIPTION	L317		
		RF ASSEMBLY			MISCELLANEOUS
		19D416693G1 138 - 155 MHz FLOATING GRD		19E500969G1	Casting.
		19D416693G2 150.8 - 184 MHz FLOATING GRD 19D416693G7 138 - 155 MHz NON FLOATING GRD		19C320251P1 19B209209P305	Cover. Tap screw, Phillips POZIDRIV [®] : No. 6 - 32 x 5 / 16.
		19D416693G8 150.8 - 174 MHz NON FLOATING GRD			(Secures cover).
A301A		ANTENNA INPUT BOARD 19B219680G1		19B201074P304	Tap screw, Phillips POZIDRIV [®] : No. 6 - 32 x 1/4. (Used with A301 - A303).
		CAPACITORS			MIF ASSEMBLY
C1	19A700015P45	Silver mica: 470 pF ±5%, 250 VDCW.			19C320153G1
C2	19A700005P7	Polyester: 0.01 uF ± 10%, 50 VDCW.			CAPACITORS
		JACKS AND RECEPTACLES	C501	19A116655P19	Ceramic disc: 1000 pF ± 20%, 1000 VDCW; sim to RMC Type JF Discap.
J1	7104941P16	Jack, phono: coaxial.	C502	19A700012P2	Variable, ceramic: 2.5 to 20 pF 200 VDCW, temp coef – 250 – 700 PPM; sim to Panasonic ECXIZW20X32.
		RESISTORS	C504	19A116656P27K0	Ceramic disc: 27 pF ± 10%, 500 VDCW, temp coef 0 PPM.
R1	19A700106P79	Composition: 4.7K ohms + 5%, 1/4 w.	C505	19A700105P46	Mica: 270 pF ±5%, 500 VDCW.
A301B		ANTENNA INPUT PLATE	C506	19A700005P7	Polyester: 0.01 uF ± 10%, 50 VDCW.
		19A137683G1	C508	19A700005P9	Polyester: 0.022 uF ± 10%, 50 VDCW.
		JACKS AND RECEPTACLES	C509	5496267P10	Tantalum: 22 uF ±20%, 15 VDCW; sim to Sprague Type 150D.
J1	7104941P20	Jack, phono: coaxial.	C521	19A700012P1	Variable, ceramic: 2 to 10 pF, 200 VDCW, temp coef – 350 to + 500 PPM; sim to Panasonic ECV - 12W10X32.
R1	19A700106P79		C523		(Part of 2502).
A302		COMPONENT BOARD A302 19B226512G1 138 - 155 MHz	C524 thru	19A700005P9	Polyester: 0.022 uF ±20%, 50 VDCW.
and		A302 195226512631 138 - 155 MHz A303 19522651262 150.8 - 174 MHz	C527		
A303			C528	5490008P139	Silver mica: 330 pF ± 10%, 50 VDCW, sim to Electro Motive Type DM - 15.
L305	19B216112G20	Coil.	C529	19A116655P19	Ceramic disc: 1000 pF + 20%, 1000 VDCW; sim to
L315	19B216112G21	Coil.	0.025		RMC Type JF Discap.
			FL501	19B219573G3	
P301	5491689P85	CABLES CABLES		13521307000	Resonator B - 11,196.024 kHz.
			FL502		(Part of FL501).
C301		CAPACITORS			JACKS AND RECEPTACLES
C301 thru C305		Includes:	J501	4033513P1	Contact, electrical: sim to Bead Chain L93 - 4.
	19C328755P3	Screw.	J502	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF - 1058.
	19A143476G2	Nut: thd. size No. 8 - 32.	J523	19A116975P1	Contact, electrical.
C306* and		Includes:	and J524		
C307*	19C328755P3	Screw. (Added to G2 by REV C).			INDUCTORS
	4036765G12	Screw. (Deleted in G2 by REV C).	L501	19A129280P1	Coll.
	19A143476G2	Nut: thd. size no. 8 - 32.	L502	7488079P48	Coil. (Part of printed wire board 19C321054P1) Coil, RF: 27 uH 10%, 1.4 ohms DC res. max; sim
C308	5495581P11	Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JR Discap.	L504		to Jeffers 4422 - 9.
C325	19B209488P1	Ceramic: 6.8 pF ±20%, 500 VDCW; sim to Allen Bradley Style FA5D.	L505	19C320141P30	
C326	19B209488P2	Ceramic: 1000 pf - 10 + 100%, 500 VDCW; sim to	L506	5493185P9 19A700103P1	Tuning slug.
		Allen Bradley Style FA5D.		19A/00103P1	Core toroidal, ferrite. (Part of Z502).
		CAPACITORS	L520 L521	19C320141P6	Coil.
L301	19B216112G19	Coil.	2021	5493185P9	Tuning slug.
L302 thru L304	19B216112G11	Coil.			

SYMBOL	PART NO.	DESCRIPTION	SYMBOL	PART NO.	DESCRIPTION
		TRANSISTORS			RECEIVER MODIFICATION KIT
Q501	19A702058P1	N Type, field effect; sim to Type 2N4391.			19A129750G1
	19A116818P4	N Channel, field effect.			DIODES AND RECTIFIERS
Q520	19A110818F4	N Channel, heid effect.	CR2301	19A116925P1	Silicon.
R501	3R151P471J	RESISTORS			RESISTORS
R503	19A700106P33	Composition: 470 onms $\pm 5\%$, 18 w.	R2301	19A700106P95	Composition: 22K ohms ±5%, 1/4 w.
			R2302	19A700106P59	Composition: 680 ohms ±5%, 1/4 w.
R520	19A700106P87	Composition: 10K ohms ± 5%, 1/8 w.			
R521	19A700106P77	Composition: 3.9Kohms ± 5%, 1/8 w.			CABLES
R522	19A700106P47	Composition: 220 ohms ±5%, 1/8 w.	W2301	19B219999G2	Cable, RF: approx. 1 foot long. Includes: (1) 5496078P2 connector.
R523	19A700106P31	Composition: 47 ohms ± 5%, 1/8 w.			5496078F2 connector.
		NETWORKS			DFE MODIFICATION KIT 19A129750G2
Z502	19C320141P20	Coil. UHS PRE - AMPLIFIER BOARD			
		19C320215G1 138 - 158 MHz 19C320215G2 147 - 174 MHz			
		CAPACITORS			PRODUCTION CHANGES
C2301	19A116795P250K	Mica: 250 pF + 10%, 250 VDCW.			
C2302L		(Part of T2301I).			quipment to improve performance or to simplify circuits a "Revision Letter", which is stamped after the model
C2302H		(Part of T2301H).		number of the un	it. The revision stamped on the unit includes all pre -
C2303	19A116655P19	Ceramic disc: 1000 pF + 20%, 1000 VDCW; sim to		vious revisions. F fected by these r	Refer to the Parts List for descriptions of parts af - evisions.
thru C2306		RMC Type JF Discap.		-	
					<u>Mixer/IF Board 19C331099G1</u>
J2301	19A700049P2	JACKS AND RECEPTACLES Connector, receptacle; 500 VDCW maximum; sim to			Transistor Q520 (19A116818P1) is obsolete. Changed Q520 to 19A116818P4 and added capacitor C531.
		NTTF - 1058.			(19A702236P32) 18 pF from Q520-S to ground. Mixer / IF 19C320153G1
		PLUGS			RF Assembly 19D416693G1,2
P2301	19A702402P2	Contact, electrical; sim to AMP 42827 - 2.			
P2302		(Part of W2302).			Preamplifier Assembly 19C230215G1 , 2 Incorporated in initial shipment.
					RF Assembly 19D416693G2
Q2301	19A116818P1	N Channel, field effect.		T	Fo improve band end tuning. Changed C306 and C307.
		RESISTORS			
R2301	19A700106P39	Composition: 100 ohms ± 5%, 1/8 w.			
R2303	19A700106P87	Composition: 10K ohms ± 5%, 1/8 w.			
R2304	3R152P752J	Composition: 7.5K ohms ± 5%, 1/8 w.			
R2305	3R152P300J	Composition: 30 ohms \pm 5%, 1/8 w.			
	4002004 11000				
T2301L	19C320141P22	Coil.			
T2301H	19C320141P21	Coil.			
T2302	19A127108G1	Coil.			
		CABLES			
W2302	5491689P85	Cable, RF: approx. 4 inches long. (includes P2302).			
		MISCELLANEOUS			
	19B219470P2	Shield.			
	19A701544P8	Can. (Used with L505, L521, Z502 and T2301 on PRE - AMPLIFIER Board).			
	4031594P1	Insulator. (Located under C502, C521).			
	4035306P23	Washer, fiber. (Located under J502).			
	4035306P11	Washer, fiber: 1/8 dia. (Located under Q520).			

PARTS LIST

- NOTE

Variable capacitor C521 does not require adjustment when performing normal alignment. If the four-pole monolithic crystal filter is replaced, then adjustment of C521 is necessary for optimum IF response.

IF Amplifier

IF amplifier Q520 is a dual-gate FET. The filter output is applied to Gate 1 of the amplifier, and the output is taken from the drain. The biasing on Gate 2 and the drain load determines the gain of the stage. The amplifier provides approximately 20 dB of IF gain.

The output of Q520 is coupled through impedance matching network L521, and C528 and coupling capacitor C529 and feed-through capacitor C325 to the next IF stage on to the MIF switch in Dual Front End Applications

Supply voltage for the RF amplifier and MIF board is supplied through feed-through capacitor C326.

		PARTS LIST	SYMBOL	PART NO.	DESCRIPTION
		MIF ASSEMBLY 19C331099G1 11.2 MHz IF 19C331099G2 9.4 MHz IF	R501	3R151P471J	
		ISSUE 6	R503 R520	19A700106P33 19A700106P87 19A700106P77	Composition: 56 ohms \pm 5%, 1/4 w. Composition: 10K ohms \pm 5%, 1/4 w.
SYMBOL	PART NO.	DESCRIPTION	R521 R522 R523	19A700106P47 19A700106P31	Composition: 3.9K ohms ± 5%, 1/4 w. Composition: 220 ohms ± 5%, 1/4 w. Composition: 47 ohms ± 5%, 1/4 w.
			Z502	19C320141P20	FILTER Coil.
C501 C502	19A700233P7 19A700012P2	Ceramic: 1000 pF ±20%, 50 VDCW. Variable, ceramic: 2.5 to 20 pF 200 VDCW, temp coef –250 –700 PPM; sim to Panasonic ECXIZW20X32.		19B219470P2	MISCELLANEOUS
C504	19A701624P18	Ceramic, disc: 27 pF ±5%, 500 VDCW, temp coef, 0 PPM ±30.		19A701544P8	Can, drawn aluminum.
C505A	19A700105P46	Mica: 270 pF ±5T, 500 VDCW. (Used in G1).		4031594P1	Insulator.
	19A700105P50	Mica: 390 pF ±5%, 500 VDCW. (Used in G1).		4035306P23	Washer, fiber.
C505B				4035306P11	Washer, fiber: 1/8 dia.
C506	T644ACP310K	Polyester: .010 uF ± 10%, 50 VDCW.			
C508	T644ACP322K	Polyester: .022 uF ± 10%, 50 VDCW.			
C509	19A701534P8	Tantalum: 22 uF ± 20%, 16 VDCW.			
C521	19A700012P1	Variable, ceramic: 2 to 10 pF, 200 VDCW, temp coef - 350 to +500 PPM; sim to Panasonic ECV - IZW10X32.			
C523 C524 thru C527	T644ACP322K	(Part of Z502.) Polyester: .022 uF ± 10%, 50 VDCW.			
C528A	5490008P139	Silver mica: 330 pf ± 10%, 500 VDCW; sim to Electro Motive Type DM-15. (Used in G1).			
C528B	19A700105P50	Mica: 390 pF ±5%, 500 VDCW. (Used in G2).			
C529	19A700233P7	Ceramic: 1000 pF ± 20%, 50 VDCW.			
C530	19A700105P17	Mica: 22 pF, 500 VDCW. (Used in G2).			
*C531	19A702236P32	Ceramic: 18pF ±5% temp coef 0 ± 30 PPM/°C.			
FL501A	19B219573G3				
FL501B	19B219574G6	Crystal, freq: Resonator A - 9400.000 KHz Resonator B - 9396.024 KHz. (Used in G2).			
FL502A		(Part of FL501A). (Used in G1).			
FL502B		(Part of FL501B). (Used in G2).			
	402254254	JACKS Contact, electrical: sim to Bead Chain L93 -4.			
J501 J502	4033513P1 19A700049P2	Contact, electrical: sim to Bead Chain L93 - 4. Connector, receptacle; 500 VDCW maximum; sim to			
J523	19A116975P1	NTTF - 1058. Contact, electrical.			
and J524		INDUCTORS			
L501	19A129280P1	Coil.			
L501	107(12020011	Coil. (Part of printed wire board).			
L502 L504	7488079P48	Coil, RF: 27 uH 10%, 1.4 ohms DC res. max; sim. to Jeffers 4422 - 9.			
L505	19C320141P30	Coil.			
L506	19A700103P1	Torroidal core.			
L520		(Part of Z502).			
L521	19C320141P6	Coil.			
0504	10470005001	TRANSISTORS			
Q501	19A702058P1 19A116818P4	N - Channel, field effect; sim to 2N4391.			
*Q520	13411081824	N Channel, field effect.			
toolupoluc		ETED OR CHANGED BY PRODUCTION CHANGES	L	I	

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

LBI-4980